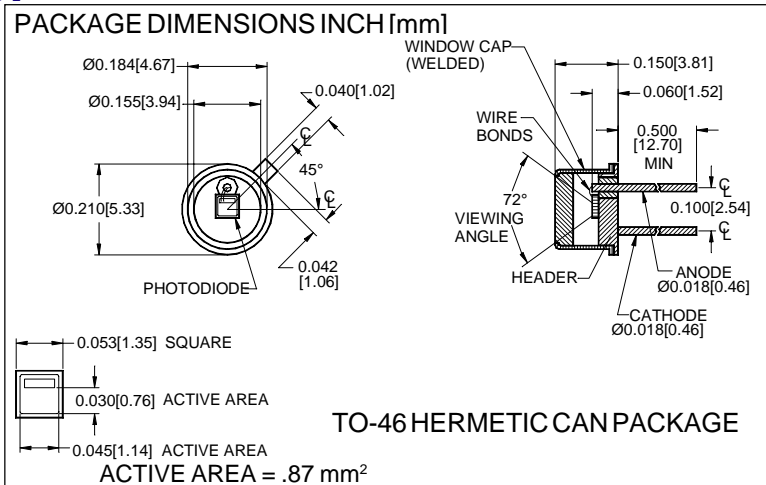


PHOTONIC DETECTORS INC.

Silicon Photodiode, Blue Enhanced Photoconductive Type PDB-C102



FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current

DESCRIPTION

The **PDB-C102** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-46 metal can with a flat window.

APPLICATIONS

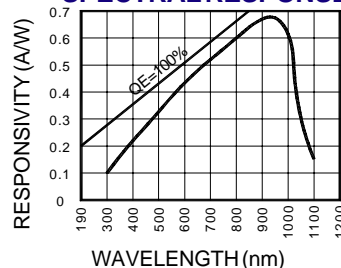
- Instrumentation
- Character recognition
- Laser detection
- Fiber optic

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V_{BR}	Reverse Voltage		100	V
T_{STG}	Storage Temperature	-55	+150	°C
T_O	Operating Temperature Range	-40	+125	°C
T_S	Soldering Temperature*		+240	°C
I_L	Light Current		0.5	mA

*1/16 inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{SC}	Short Circuit Current	H = 100 fc, 2850 K	8.5	9		μA
I_D	Dark Current	H = 0, $V_R = 10$ V		45	150	pA
R_{SH}	Shunt Resistance	H = 0, $V_R = 10$ mV	0.5	2		G Ω
TCR_{SH}	RSH Temp. Coefficient	H = 0, $V_R = 10$ mV		-8		% / °C
C_J	Junction Capacitance	H = 0, $V_R = 10$ V**		4		pF
λ_{range}	Spectral Application Range	Spot Scan	350		1100	nm
λ_p	Spectral Response - Peak	Spot Scan		950		nm
V_{BR}	Breakdown Voltage	I = 10 μA	100	125		V
NEP	Noise Equivalent Power	$V_R = 10$ V @ Peak		10×10^{-14}		W/ \sqrt{Hz}
tr	Response Time	RL = 1 K Ω $V_R = 50$ V		3.0		nS